

# Radiation Measurements in the SPS target area TCC2

- Radiation field
- Radiation quantities
  - ↖ Dosimetry = absorbed dose measurement
    - ◆ depends on material
    - ◆ depends on particle type and energy
  - ↖ Particle-flux measurements
    - ◆ activation detectors
    - ◆ silicon detectors

# Radiation fields around HEP conversion targets

- ↖ micro-waves ( problems of EMC )
- ↖ low-energy and high-energy gamma's
- ↖ Neutrons (thermal + evap.~ 1 MeV + spal.~ 15 MeV)
- ↖ other hadrons ( $p^+$ ,  $\alpha$ ,  $\pi$  ...), some of high energies (HEP)
- ↖ electrons ( and positrons )
- ↖ other leptons ( $\mu$ ,  $\nu$ )

## Radiation quantities :

- **Fluence** = number of particles / surface area [ part / cm<sup>2</sup> ]
- **Exposition** = created charge / mass unit [ C / kg ],  
or per volume unit [ C / cm<sup>3</sup> ]
- **Absorbed Dose** = deposited energy per mass unit  
[ J / kg = Gy = gray = 100 rad ]
- **Linear Energy Transfert** = deposited energy per path length  
( LET or dE/dx )  
[ MeV /cm or MeV.cm<sup>2</sup> / g ]

## Exposition measurement

**Exposition** = deposited charge per unit mass [ C / kg ],  
or volume [ C / cm<sup>3</sup> ]

1 Röntgen = 1 e.s.u./cm<sup>3</sup> of air = 8.77 mGy (in air)

- Gaseous ionisation chamber (current  $\sim\sim$  dose-rate) = **PMI**
- Solid ionisation chambers :
  - PIN diode (reverse current  $\sim\sim$  dose-rate)
  - MOSFET (  $\Delta V_b \sim\sim$  absorbed dose)

## Measurement of Absorbed Dose

**Absorbed Dose** = deposited energy per unit mass

$$[ 1 \text{ J / kg} = 1 \text{ Gy} = \text{one gray} ]$$

$$100 \text{ erg/gr} = 1 \text{ rad} = 1 \text{ cGy} ]$$

↖ Calorimeter = only absolute means  
measure of heat in a given material  
complex and delicate

$$[ \text{Note: } 1 \text{ Gy/s} = 1 \text{ watt/kg} ]$$

↖ many other secondary means...

## Dosimeters (in TCC2)

**PAD** = polymer-alanine dosimeter

**RPL** = radio-photo-luminescent dosi.

**HPD** = hydrogen-pressure dosimeter

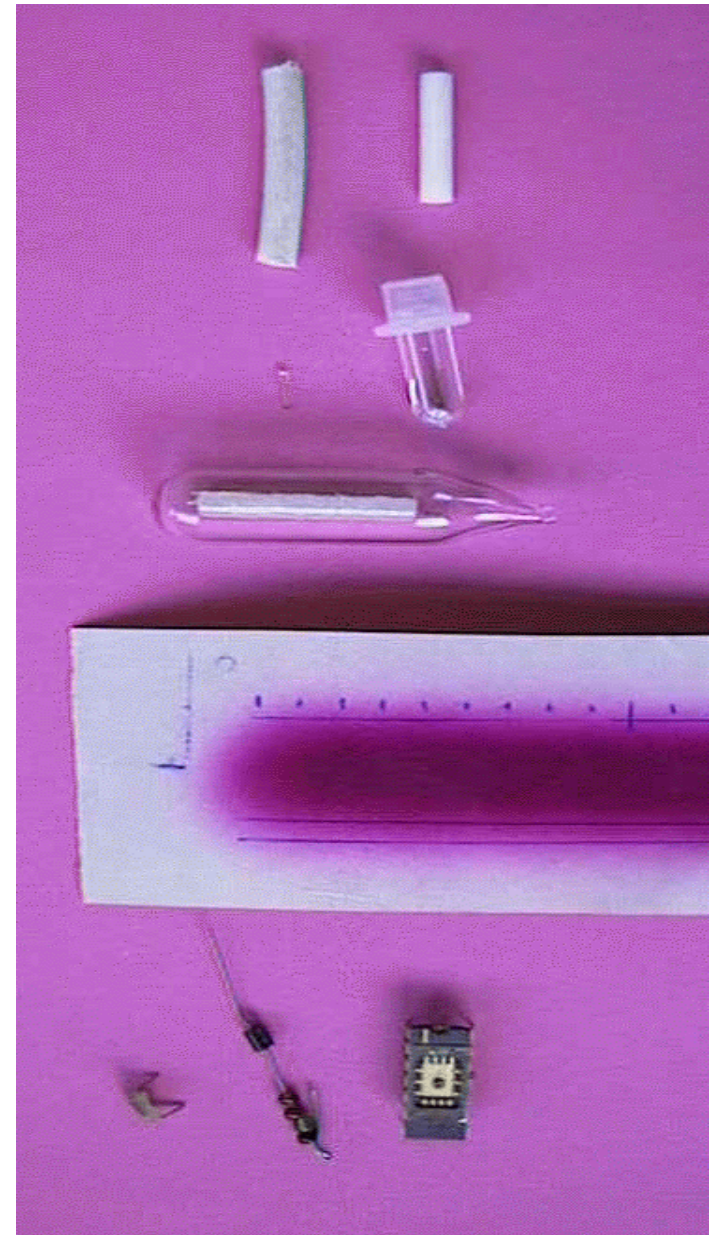
**Risø** = radio-chromic film

**Photo-diodes** ; for dose-rate measur.

**PIN diodes** ; for neutron measur.

**Radfet** = MOS-FET dosimeter

**Activation foils**



## Absorbed Dose in Various Materials

To be able to calculate the dose in any material, one must know

- the exposure (in R) or the dose in air (in Gy)
- the type(s) of radiation
- the energy-spectrum of the radiation(s)
- the linear energy absorption coefficient(s) [  $dE/dx$  in MeV/cm ]
- the composition of the material, its density (or elements)

## Typical dose measurements around HEP accelerators

$\gamma$  + neutrons + HEP

Usually : **1 Gy (ionisation) +  $1\sim 3 \times 10^{10}$  n/cm<sup>2</sup> +  $5\sim 10 \times 10^8$  HEP/cm<sup>2</sup>**

↖ dose in H<sub>2</sub>O or CH<sub>2</sub> =  $f_1 \times d_\gamma + f_2 \times d_n$  (by convention,  $f_1 = f_2 = 1$  ;  $f_i$  = dose factors)

Usually, neutron-dose  $\sim 5\%$  of gamma-dose

↖ dose in Si or SiO<sub>2</sub> =  $(\sim f_1 \times) d_\gamma + f_3 \times d_{nth} + f_4 \times d_{nE} + f_5 \times d_{HEP}$

In Si, usually, neutron-dose  $\sim 1\%$  of gamma-dose

↖ equiv. dose (Sv) =  $(\sim Q_1 \times) d_\gamma + Q_2 \times d_{nth} + Q_3 \times d_{nE} + Q_4 \times d_{HEP}$

In many cases, neutron-equiv.dose  $\sim$  gamma-equiv.dose

$Q_i$  = quality factors



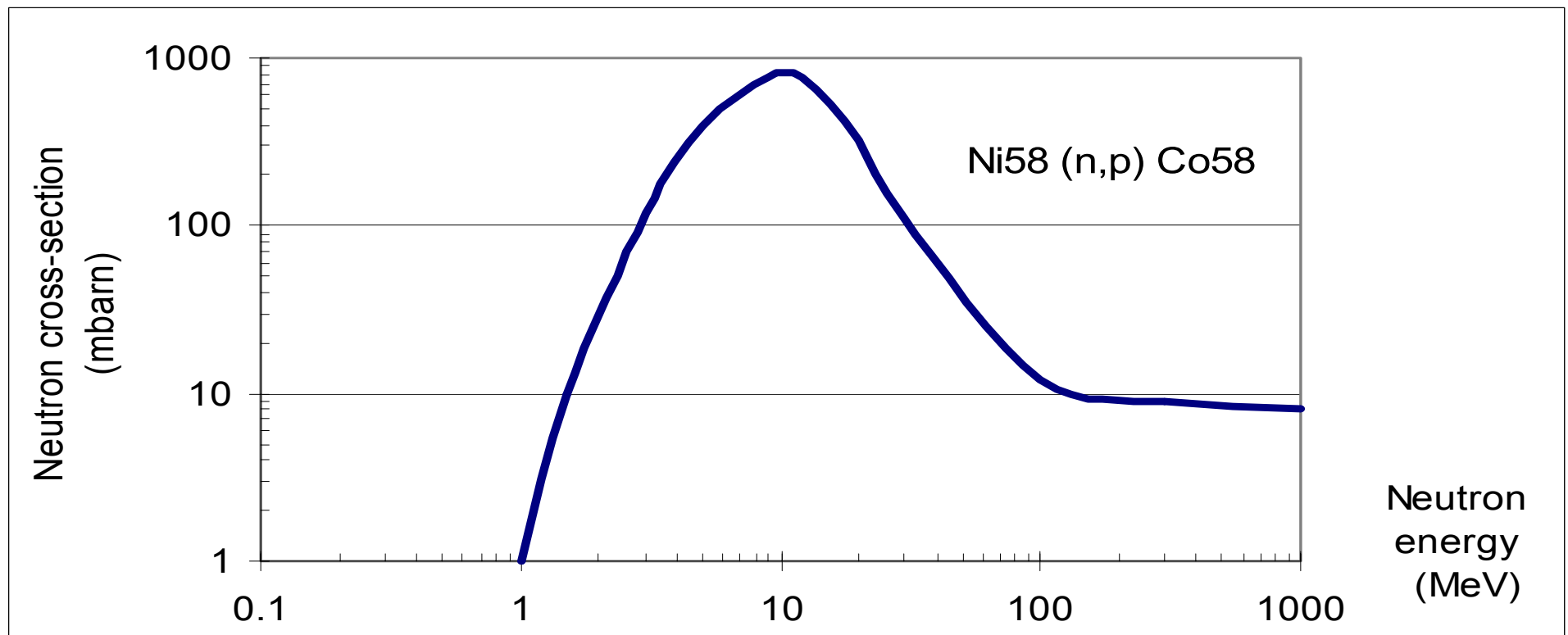
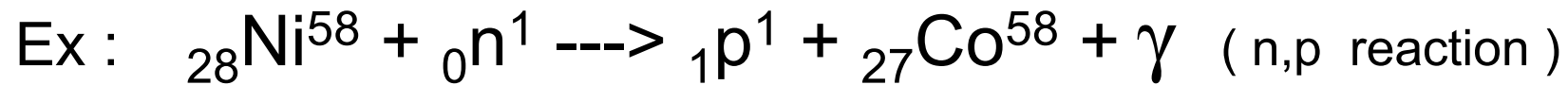
## Fluence measurement

- If excitations or ionisations (←electromagnetic radiation)
  - photodiodes, Faraday cups...
- If activation (← neutrons, protons...)
  - activation detectors (foils of pure material)
- If induced defects
  - $\alpha$  of silicon (  $\Delta I$  / fluence.unit volume )
  - change of resistivity → PIN diodes

Note : flux unit = part / cm<sup>2</sup> . s

## Fluence measurement by activation foils

$$\text{Activity} = A = \phi \cdot \sigma \cdot N_0 \cdot [1 - \exp(-\lambda \cdot t_i)] \cdot \exp(-\lambda \cdot t_e)$$



# Silicon diodes for Neutron measurement

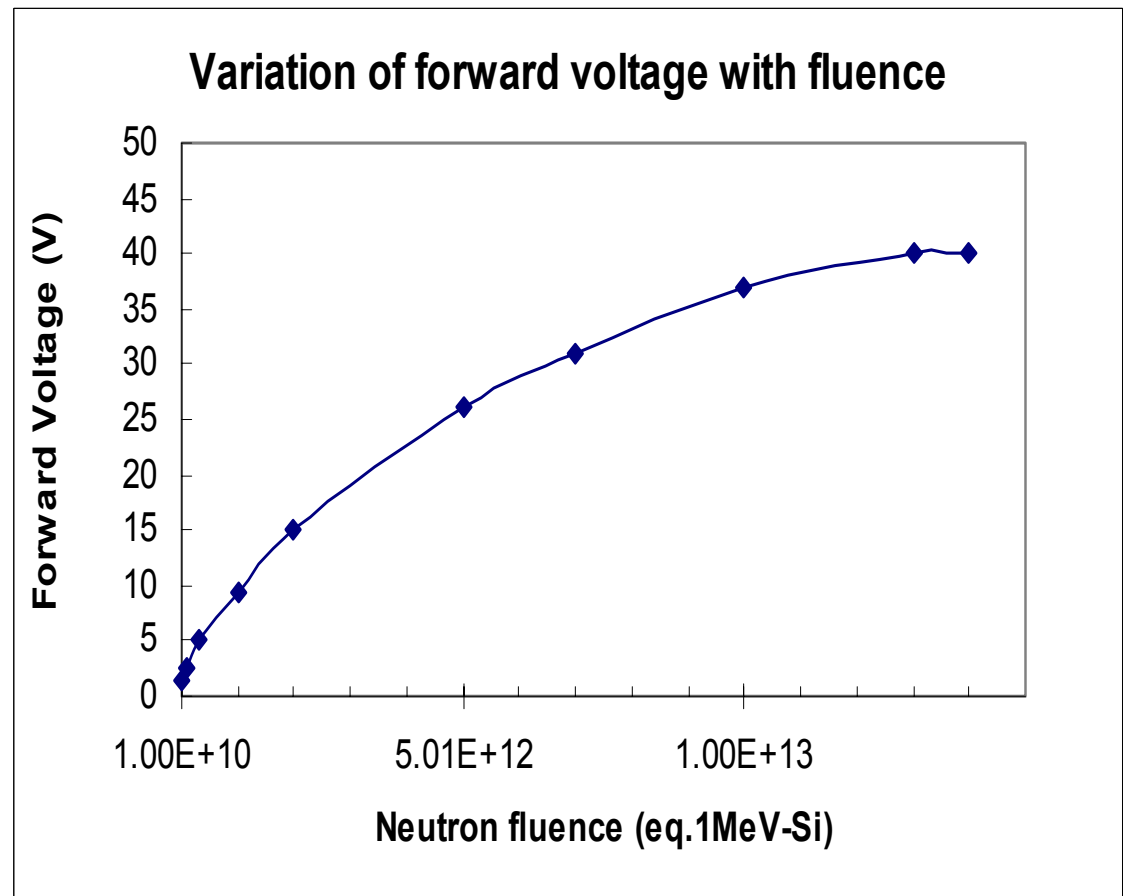
Diode type = DN 156 by Harshaw (USA)

Usage of Kerma factors according to ASTM E-722:

$$\Phi_{\text{eq.1MeV(Si)}} = \frac{\int \Phi(E) \cdot K(E) \cdot dE}{K(1\text{MeV})}$$

Calibration curve of the type:

$$U_f = U_{f0} + U_{\text{sat}} [1 - \exp(-\xi\Phi)]$$



# Conclusions / radiation measurement

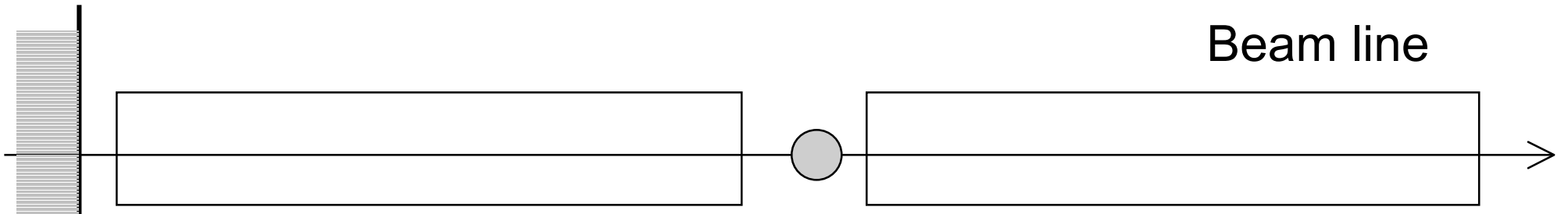
- Measurement of absorbed dose

- ↖ depends on the radiation types and energy spectra,
- ↖ depend on the considered material !

- Measurement of particle fluences

- ↖ must be adapted to particle type(s) and energies
- ↖ must be adapted to the intensity and duration of irradiation

# Results in TCC2 for 2001 $\pm 30\%$



Beam line

PMI-TC-02

**2400 Gy**

**2e13 n.cm-2**

PMI-TC-03

**2650 Gy**

**3.5e13 n.cm-2**

PMI-TC-01

**950 Gy**

**5e12 n.cm-2**

PMI-TC-04

**780 Gy**

**3e12 n.cm-2**

PMI-N4

**500 Gy**

**3e12 n.cm-2**